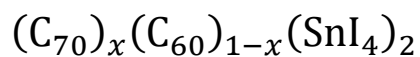


Supporting Information: Generalizing the Chiral Self-Assembly of
Spheres and Tetrahedra to Non-Spherical and Polydisperse Molecules in



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Experimental

1. Synthesis

$C_{70}(SnI_4)_2$ was synthesized by dissolving 50.15 mg C_{70} (99%, Proactive Molecular Research) and 2506.86 mg SnI_4 (95%, Alfa-Aesar) in a mixture of 50 mL toluene (ACS, Sigma-Aldrich) and 60 mL 1,2-dichlorobenzene (99%, Acros Organics) using sonication. 25 mL of benzene followed by ~400 mL pentane (98%, Sigma-Aldrich) were layered on top of the dichlorobenzene-toluene solution and left undisturbed so the solution would mix. Two phases of crystals grew: dull black hexagonally shaped crystals of $C_{70}(SnI_4)_2$ as well as shiny black rectangular crystals of another phase that we hypothesize is a C_{70} -pentane intercalation compound.

$(C_{70})_{0.75}(C_{60})_{0.25}(SnI_4)_2$ was synthesized by dissolving 2.57 mg C_{60} (99.5%, Proactive Molecular Research), 8.80 mg C_{70} , and 504.0 mg SnI_4 in a mixture of 10 mL toluene and 10 mL 1,2-dichlorobenzene using sonication. ~90 mL pentane was layered on top, and the solution was placed in a 4 °C refrigerator and left undisturbed while the solutions mixed. Dull black crystals of $(C_{70})_{0.75}(C_{60})_{0.25}(SnI_4)_2$ were the only phase that formed.

$(C_{70})_{0.5}(C_{60})_{0.5}(SnI_4)_2$ was synthesized by dissolving 5.12 mg C_{60} , 6.11 mg C_{70} , and 503.1 mg SnI_4 in a mixture of 10 mL toluene and 10 mL 1,2-dichlorobenzene using sonication. ~90 mL pentane was layered on top, and the solution was placed in a 4 °C refrigerator and left undisturbed while the solutions mixed. Dull black crystals of $(C_{70})_{0.5}(C_{60})_{0.5}(SnI_4)_2$ were the only phase that formed.

$(C_{70})_{0.25}(C_{60})_{0.75}(SnI_4)_2$ was synthesized by dissolving 7.47 mg C_{60} , 2.93 mg C_{70} , and 504.0 mg SnI_4 in a mixture of 16 mL toluene and 8 mL 1,2-dichlorobenzene using sonication. ~85 mL pentane was layered on top, and the solution was placed in a 4 °C refrigerator and left

undisturbed while the solutions mixed. Dull black crystals of $(C_{70})_{0.25}(C_{60})_{0.75}(SnI_4)_2$ were the only phase that formed.

2. Characterization

Powder X-ray diffraction patterns were collected on a Bruker D8 Advance Eco diffractometer using Cu $k\alpha$ radiation ($\lambda = 1.5406 \text{ \AA}$). To prepare the powder, several crystals of $(C_{70})_x(C_{60})_{1-x}(SnI_4)_2$ were placed on a Bruker miscut Si low background slide and crushed. Lattice parameters were extracted using Le Bail refinements performed with TOPAS.¹

Single crystal X-ray diffraction data were collected on a Bruker APEX-II Duo CCD diffractometer or a Bruker D8 Venture diffractometer with a Photon III detector, both using Mo $k\alpha$ ($\lambda = 0.7107 \text{ \AA}$) radiation. Crystals were mounted with Parabar 10312 oil (Hampton Scientific) on Kapton loops (MiTiGen). The data are integrated using SAINT (Bruker AXS) and scaled with a multiscan absorption correction using SADABS (Bruker AXS). The $P4_332$ (#212) or $P4_132$ (#213) space groups were identified through systematic absences using XPREP (Bruker AXS). The initial solution was found using the intrinsic phasing method of the SHELXT program² and the structure was refined using the least squares algorithm of the SHELXL program³ in the OLEX2 GUI.⁴ The absolute configuration (handedness) of the crystal was resolved using the anomalous dispersion of X-rays, and the correct enantiomer was identified by a Flack parameter of approximately zero.⁵

To refine the single crystal structure for $C_{70}(SnI_4)_2$, a C_{70} molecule was imported from ref 6 (ICSD collection code 75506) using the *importfrag* command in OLEX2 and refined as a rigid body. The coordinates of the C atoms were restrained using an AFIX 9 instruction in SHELXL, which allows the C_{70} molecule to uniformly grow or shrink but fixes the relative position of the C atoms. The occupancy of each C atom was fixed at 1/6 to account for disorder about symmetry

elements. Anisotropic thermal parameters were used for the Sn and I atoms. The C atoms were refined isotropically. Every C atom is restrained to have identical thermal parameters using the EADP instruction in SHELXL.

The single crystal structures of $(C_{70})_x(C_{60})_{1-x}(SnI_4)_2$ ($x = 0.25, 0.5, 0.75$) were refined similarly to that of $C_{70}(SnI_4)_2$. The C_{70} molecule was refined as a rigid body using the AFIX 9 instruction, with the occupancy of each C atom in C_{70} set to $x/6$ to account for disorder about symmetry elements where x is the nominal fraction of C_{70} (for instance, the occupancy is set to $1/24$ for $x = 0.25$). To account for the presence of C_{60} , the structure of the C_{60} molecule was taken from the Idealized Molecular Geometry Library.⁷ The thermal parameters of each C atom in C_{70} were restrained to be identical to one another using the EADP instruction. Like C_{70} , the C_{60} molecule was refined as a rigid body using the AFIX 9 instruction. The occupancy of each C atom in C_{60} was fixed as $(1 - x)/6$ to account for disorder about symmetry elements (for instance, the occupancy is set to $3/24$ for $x = 0.25$). The thermal parameters of each C atom in C_{60} were restrained to be identical to one another using the EADP instruction. In the $x = 0.25$ and $x = .5$ structures, one of the two symmetry distinct I atoms resolved with disorder, and the occupancies of the two sites were constrained to sum to unity.

Crystal structure images are visualized using VESTA.⁸ Asymmetric units in Figures S2-S5 are visualized using OLEX2.⁴

Additional Figures

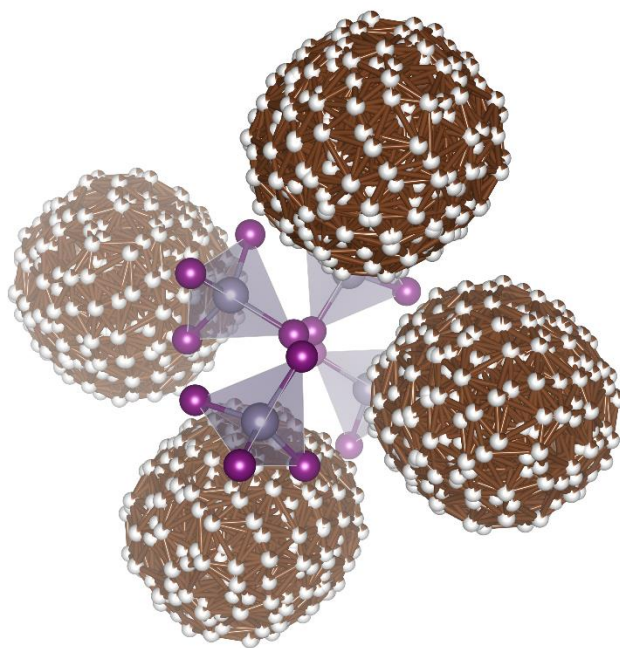


Figure S1: Depiction of 4₁ screw axis in C₇₀(SnI₄)₂ with disordered C₇₀ molecules shown.

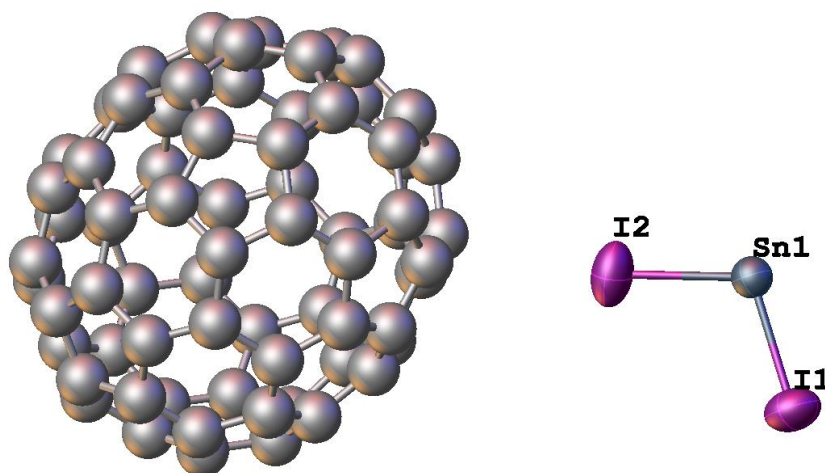


Figure S2: Asymmetric unit for single crystal structure of C₇₀(SnI₄)₂. Atoms are represented as 50% probability thermal displacement parameters.

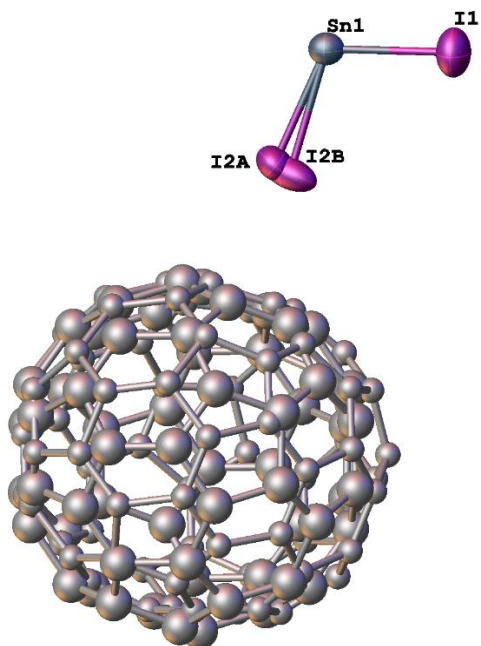


Figure S3: Asymmetric unit for single crystal structure of $(C_{70})_{0.25}(C_{60})_{0.75}(SnI_4)_2$. Atoms are represented as 50% probability thermal displacement parameters.

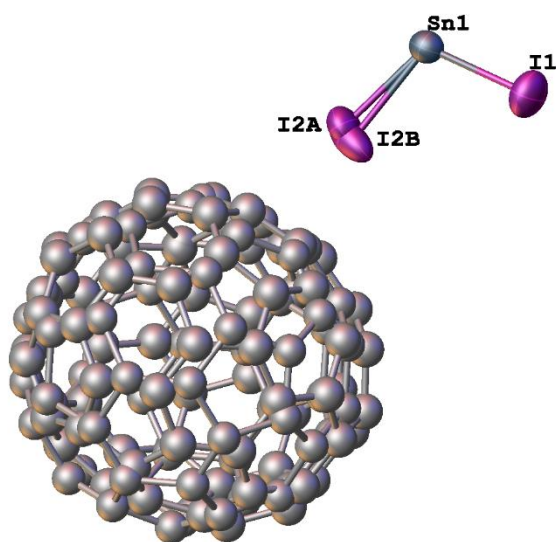


Figure S4: Asymmetric unit for single crystal structure of $(C_{70})_{0.5}(C_{60})_{0.5}(SnI_4)_2$. Atoms are represented as 50% probability thermal displacement parameters.

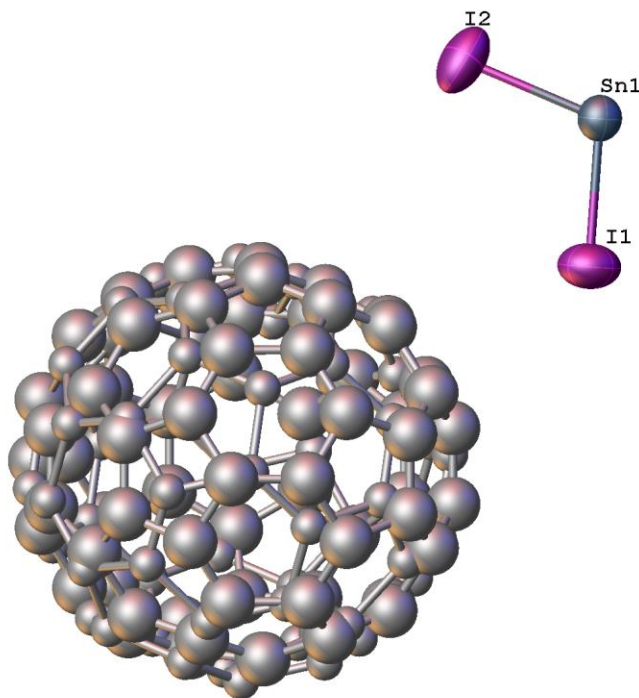


Figure S5: Asymmetric unit for single crystal structure of $(\text{C}_{70})_{0.75}(\text{C}_{60})_{0.25}(\text{SnI}_4)_2$. Atoms are represented as 50% probability thermal displacement parameters.

Additional Tables

Table S1: Crystal data and structure refinement for $C_{70}(SnI_4)_2$.

Empirical formula	$C_{70}I_8Sn_2$
Formula weight	2093.31
Temperature/K	294.99
Crystal system	cubic
Space group	$P4_132$
$a/\text{\AA}$	17.1493(7)
Volume/ \AA^3	5043.6(6)
Z	4
$\rho_{\text{calc}}/\text{g/cm}^3$	2.757
μ/mm^{-1}	5.937
$F(000)$	3776.0
Crystal size/ mm^3	$0.568 \times 0.536 \times 0.284$
Radiation	$\text{MoK}\alpha$ ($\lambda = 0.71073$)
2Θ range for data collection/ $^\circ$	4.114 to 57.396
Index ranges	$-21 \leq h \leq 12, -23 \leq k \leq 22, -23 \leq l \leq 11$
Reflections collected	20622
Independent reflections	2189 [$R_{\text{int}} = 0.0310$, $R_{\text{sigma}} = 0.0158$]
Data/restraints/parameters	2189/0/24
Goodness-of-fit on F^2	1.066
Final R indexes [$I \geq 2\sigma(I)$]	$R_1 = 0.0679$, $wR_2 = 0.1910$
Final R indexes [all data]	$R_1 = 0.0911$, $wR_2 = 0.2144$
Largest diff. peak/hole / $e \text{\AA}^{-3}$	0.93/-0.72
Flack parameter	-0.04(3)

Table S2: Crystal data and structure refinement for $(\text{C}_{70})_{0.25}(\text{C}_{60})_{0.75}(\text{SnI}_4)_2$.

Empirical formula	$\text{C}_{62.5}\text{I}_8\text{Sn}_2$
Formula weight	2003.23
Temperature/K	295
Crystal system	cubic
Space group	$\text{P4}_3\text{32}$
$a/\text{\AA}$	16.7390(13)
Volume/ \AA^3	4690.2(11)
Z	4
$\rho_{\text{calc}}/\text{g/cm}^3$	2.837
μ/mm^{-1}	6.377
F(000)	3596.0
Crystal size/ mm^3	$0.467 \times 0.308 \times 0.266$
Radiation	$\text{MoK}\alpha$ ($\lambda = 0.71073$)
2θ range for data collection/ $^\circ$	3.44 to 58.274
Index ranges	$-20 \leq h \leq 22, -22 \leq k \leq 22, -8 \leq l \leq 22$
Reflections collected	18754
Independent reflections	2127 [$R_{\text{int}} = 0.0585, R_{\text{sigma}} = 0.0367$]
Data/restraints/parameters	2127/0/42
Goodness-of-fit on F^2	1.163
Final R indexes [$I \geq 2\sigma(I)$]	$R_1 = 0.0759, wR_2 = 0.1507$
Final R indexes [all data]	$R_1 = 0.1277, wR_2 = 0.1725$
Largest diff. peak/hole / e \AA^{-3}	0.90/-0.81
Flack parameter	-0.08(2)

Table S3: Crystal data and structure refinement for $(C_{70})_{0.5}(C_{60})_{0.5}(SnI_4)_2$.

Empirical formula	$C_{65}I_8Sn_2$
Formula weight	2033.23
Temperature/K	295.01
Crystal system	cubic
Space group	$P4_32$
$a/\text{\AA}$	16.8763(13)
Volume/ \AA^3	4806.5(11)
Z	4
$\rho_{\text{calc}}/\text{g/cm}^3$	2.810
μ/mm^{-1}	6.225
F(000)	3656.0
Crystal size/ mm^3	$0.421 \times 0.382 \times 0.303$
Radiation	$\text{MoK}\alpha$ ($\lambda = 0.71073$)
2θ range for data collection/ $^\circ$	3.412 to 57.394
Index ranges	$-22 \leq h \leq 21$, $-22 \leq k \leq 13$, $-21 \leq l \leq 21$
Reflections collected	19074
Independent reflections	2081 [$R_{\text{int}} = 0.0387$, $R_{\text{sigma}} = 0.0239$]
Data/restraints/parameters	2081/0/42
Goodness-of-fit on F^2	1.188
Final R indexes [$I \geq 2\sigma(I)$]	$R_1 = 0.0794$, $wR_2 = 0.1478$
Final R indexes [all data]	$R_1 = 0.1241$, $wR_2 = 0.1714$
Largest diff. peak/hole / $e \text{\AA}^{-3}$	1.03/-1.13
Flack parameter	-0.10(2)

Table S4: Crystal data and structure refinement for (C₇₀)_{0.75}(C₆₀)_{0.25}(SnI₄)₂.

Empirical formula	C _{67.5} I ₈ Sn ₂
Formula weight	2063.25
Temperature/K	295
Crystal system	cubic
Space group	P4 ₃ 32
a/Å	17.0312(3)
Volume/Å ³	4940.1(3)
Z	4
ρ _{calc} /cm ³	2.774
μ/mm ⁻¹	6.059
F(000)	3716.0
Crystal size/mm ³	0.279 × 0.268 × 0.186
Radiation	MoKα (λ = 0.71073)
2Θ range for data collection/°	5.348 to 59.06
Index ranges	-17 ≤ h ≤ 22, -23 ≤ k ≤ 23, -14 ≤ l ≤ 23
Reflections collected	27967
Independent reflections	2323 [R _{int} = 0.0568, R _{sigma} = 0.0223]
Data/restraints/parameters	2323/0/32
Goodness-of-fit on F ²	1.034
Final R indexes [I ≥ 2σ (I)]	R ₁ = 0.0580, wR ₂ = 0.1532
Final R indexes [all data]	R ₁ = 0.0823, wR ₂ = 0.1761
Largest diff. peak/hole / e Å ⁻³	0.70/-0.79
Flack parameter	-0.06(3)

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